

X-ray Diffuse Scattering of the Halogen-bridged Mixed-valence Diplatinum(II,III) Complex, $\text{Pt}_2(\text{EtCS}_2)_4\text{I}$

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1. Introduction

Halogen-bridged mixed-valence diplatinum complexes $\text{Pt}_2(\text{RCS}_2)_2\text{I}$ ($\text{R}=\text{CH}_3$ (**1**), C_2H_5 (**2**), $\text{n-C}_3\text{H}_7$ (**3**)) with linear chain structures of repeating units $\{-\text{I-Pt-Pt-I}-\}$ (Fig.1) are particular interest because they are possible to take a variety of valence ordering as follows [1].

- (a) $-\text{I-Pt}^{2+}-\text{Pt}^{2+}-\text{I-Pt}^{3+}-\text{Pt}^{3+}-\text{I}-$
- (b) $-\text{I-Pt}^{2+}-\text{Pt}^{3+}-\text{I-Pt}^{3+}-\text{Pt}^{2+}-\text{I}-$
- (c) $-\text{I-Pt}^{2+}-\text{Pt}^{3+}-\text{I-Pt}^{2+}-\text{Pt}^{3+}-\text{I}-$
- (d) $-\text{I-Pt}^{2.5+}-\text{Pt}^{2.5+}-\text{I-Pt}^{2.5+}-\text{Pt}^{2.5+}-\text{I}-$

The crystals of **1** which was first reported by Bellitto *et al.* [2] exhibit anomalous electrical conducting behavior ($T < 300$ K, semiconductor; $300 \text{ K} < T < 340$ K, metallic) [3]. The variable temperature crystal structure analyses revealed dynamic disorder of the CH_3CS_2^- ligands above 270 K [4].

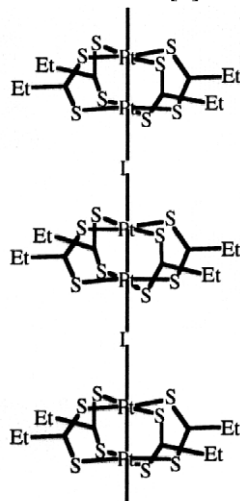


Fig. 1. Linear chain structure of $\text{Pt}_2(\text{EtCS}_2)_4\text{I}$ (**2**).

In order to elucidate the relation between the solid state behavior and the valence ordering of Pt atoms on the linear chain, the compounds **2** and **3** were synthesized and their crystal structure analyses and electrical conducting measurements were carried out [5]. The M-I transition was observed for **2** at about 200 K.

Since only the averaged structures have been provided the crystal structure analyses, we tried to measure the diffuse scattering corresponding to low-dimensional valence ordering of Pt atoms.

2. Experiment

Single crystal X-ray photographs of the compounds **1-3** were taken with a flat IP cassette or a vacuum type X-ray IP camera mounted on a 7-circle diffractometer at SPring-8 BL02B1 station. A Rigaku cold N_2 gas stream type low temperature apparatus was installed. X-ray photographs were taken by rotating crystals

around the chain axes, by using 30 keV X-ray beam monochromated by a Si(111) double crystals and focused by a mirror. X-ray rotation photographs were also taken at temperature region 24 - 300 K by using the vacuum type low-background X-ray camera developed by MAC Science Co., Ltd. and us.

3. Results and Discussion

On the rotation photographs measured for the crystals **1-3** at room temperature, diffuse scattering corresponding to twice the original cell along the linear chain structures were clearly observed (Fig. 2).

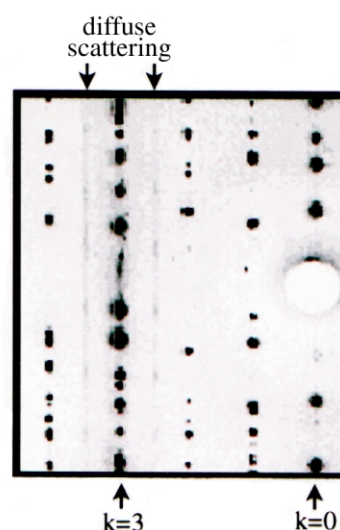


Fig. 2. Rotation photograph of $\text{Pt}_2(\text{EtCS}_2)_4\text{I}$ (**2**) at room temperature.

This strongly indicates that Pt^{2+} and Pt^{3+} are arranged alternately along the linear chain such as the valence ordering of (a) or (b) described above.

It was also revealed that although the diffuse scatterings were observed for **2** above 200 K (metallic state), but changed to the Bragg spots below 100 K (semiconductive state). Similar phenomena were observed for the crystals of **3**. These results suggest that the valences of Pt atoms are three-dimensionally ordered in the low temperature below 100 K, and seem to be consistent with the semiconductive behavior of **2**.

References

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- [2] C. Bellitto *et al.*, Inorg. Chem. **22** (1983) 444.
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- [4] K. Toriumi *et al.*, 33rd. ICCA Abstract, 419 (1998).
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